$$
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& \text { THANHISTIURE }
\end{aligned}
$$

## THE FAIRCHILD EPOXY TRANSISTOR

The transistor assembly technology described on the following pages was developed for the Electronics Industry to provide a low-cost, high-performance, reliable Silicon Planar Transistor-lower in cost than Germanium.
These devices have found wide-spread usage in product areas such as: T.V. sets, Radios, Test and Measuring Equipment, Communications and Computing Equipment.

Additional advantages obtained using this assembly technology are lead arrangements compatible with Standard TO.18s and TO.5s and excellent thermal ratings.

Since the assembly operation is similar to that of conventional metal-can transistors, special assemblies (multiple dice in one package) and optional package outines can easily be accomplished. Also, improvements in technology can be implemented without the costly and time-consuming delays normally associated with a totally-automated production line.

PROCESS FLOW DIAGRAM


STEP 1 DIE ATTAGH

1. Dif attached to COLECTOR
2. CLUB LEAD
3. EMTER BANE BASE BOND'S
MADE TO DIE


STEP 3 HEADER ASSEMBLY


STEP 2 LEAD BOND


STEP 4 HEADER ORIENTATION


STEP 5 LEAD WELD


STEP 7 POTTING


STEP 6 COATING


FINAL PRODUCT


## PRICE LIST

(1 THROUCH 4999)

|  | PACKAGE | $1-99$ | $100-999$ | $1000-4999$ |
| :--- | :--- | ---: | :--- | ---: |
| 2N3563 | TO-18 | $\$ 1.20$ | $\$ .80$ | $\$ .72$ |
| 2N3564 | TO-18 | .90 | .60 | .54 |
| 2N3565 | TO-18 | .90 | .60 | .54 |
| 2N3566 | TO-5 | 1.50 | 1.00 | .90 |
| 2N3567 | TO-5 | .90 | .60 | .54 |
| 2N3568 | TO-5 | 1.30 | .85 | .78 |
| 2N3569 | TO-5 | 1.35 | .90 | .81 |
| 2N3638 | TO-5 | .46 | .31 | .28 |
| T 2N3638A | TO-5 | 1.00 | .67 | .60 |
| † 2N3639 | TO-18 | .65 | .43 | .39 |
| + 2N3640 | TO-18 | .70 | .46 | .42 |
| 2N3641 | TO-5 | .90 | .60 | .54 |
| 2N3642 | TO-5 | .95 | .63 | .57 |
| 2N3643 | TO-5 | .95 | .63 | .57 |
| 2N3646 | TO-18 | .70 | .46 | .42 |

Effective January 15, 1965

## SHORT FORM CHARACTERIZATION

|  | $h_{\text {FE }}$ |  | @ | Ic. | LV ceo | * Cob | ${ }^{*} \mathrm{~F}^{\text {r }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | min | max |  | ma | volts | pf | Mc |
| 2N3563 | 20 | 200 |  | 8 | 12 | 1.4 | 900 |
| 2N3564 | 20 | 120 |  | 15 | 15 | 2.5 | 750 |
| 2N3565 | 150 | 600 |  | 1 | 25 | 3 | 100 |
| 2N3566 | 150 | 600 |  | 10 | 30 | 13 | 40 |
| 2N3567 | 40 | 120 |  | 150 | 40 | 13 | 60 |
| 2N3568 | 40 | 120 |  | 150 | 60 | 13 | 60 |
| 2N3569 | 100 | 300 |  | 150 | 40 | 18 | 60 |
| † 2N3638 | 30 |  |  | 50 | 25 | 12. | 150 |
| $\dagger$ 2N3638A | 30 | 180 |  | 50 | 45 | 10 | 150 |
| + 2N3639 | 30 | 120 |  | 10 | 6 | 1.85 | 750 |
| † 2N3640 | 30 | 120 |  | 10 | 12 | 1.85 | 750 |
| 2N3641 | 40 | 120 |  | 150 | 30 | 6 | 400 |
| 2N3642 | 40 | 120 |  | 150 | 45 | 6 | 400 |
| 2N3643 | 100 | 300 |  | 150 | 30 | 6 | 400 |
| 2N3646 | 30 | 120 |  | 30 | 15 | 3.3 | 550 |

